

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process) (Darlington power transistor)

# 2SD1631

Micro Motor Drive, Hammer Drive Applications

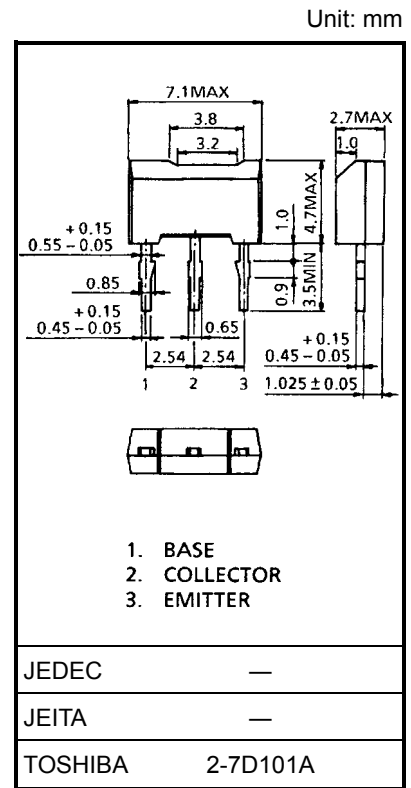
Switching Applications

Power Amplifier Applications

- High DC current gain:  $h_{FE} = 4000$  (min) ( $V_{CE} = 2\text{ V}$ ,  $I_C = 150\text{ mA}$ )
- Low saturation voltage:  $V_{CE(sat)} = 1.5\text{ V}$  (max) ( $I_C = 1\text{ A}$ ,  $I_B = 1\text{ mA}$ )

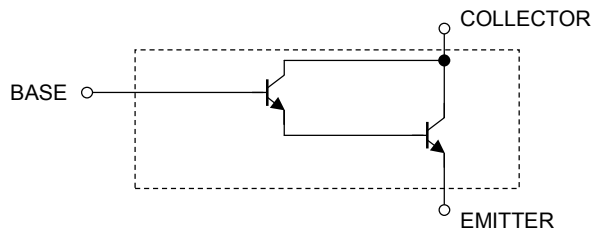
## Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	30	V
Collector-emitter voltage	$V_{CEO}$	30	V
Emitter-base voltage	$V_{EBO}$	10	V
Continuous collector current	$I_C$	1.5	A
Continuous base current	$I_B$	50	mA
Collector power dissipation	$P_C$	1000	mW
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-55 to 150	$^\circ\text{C}$



Weight: 0.2 g (typ.)

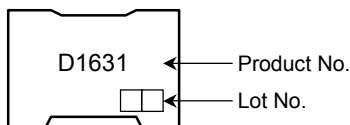
## Equivalent Circuit



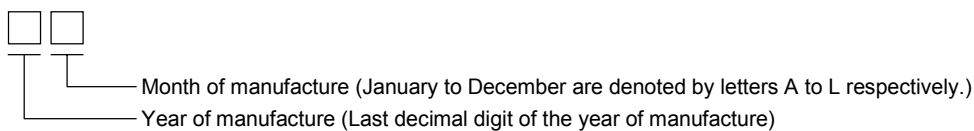
## Electrical Characteristics (Ta = 25°C)

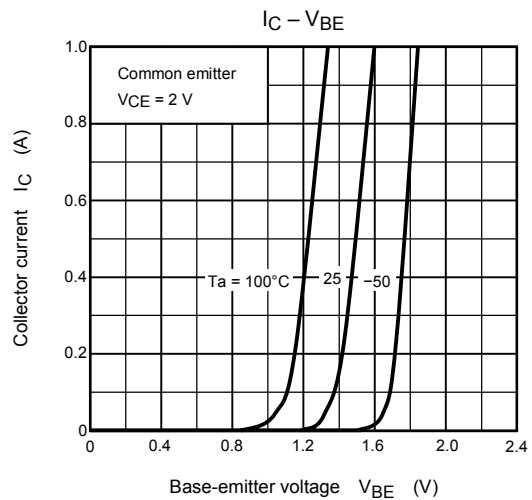
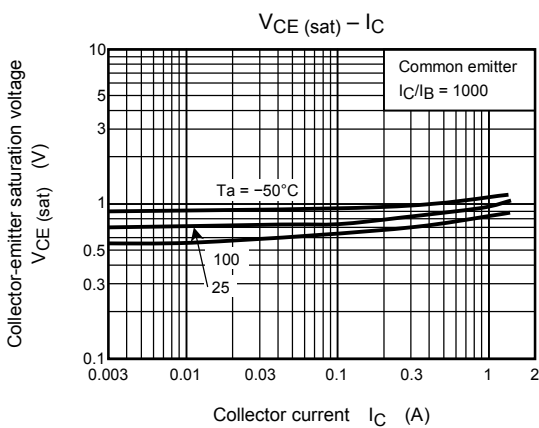
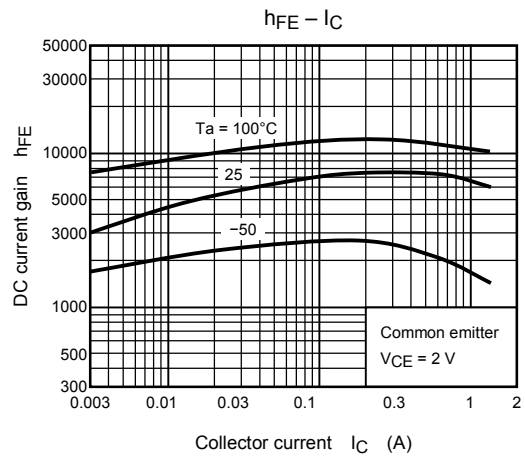
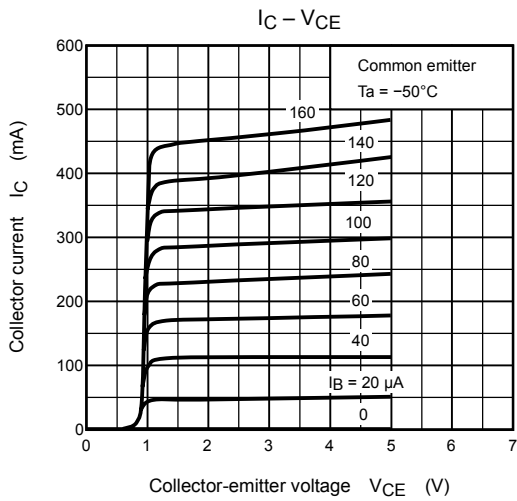
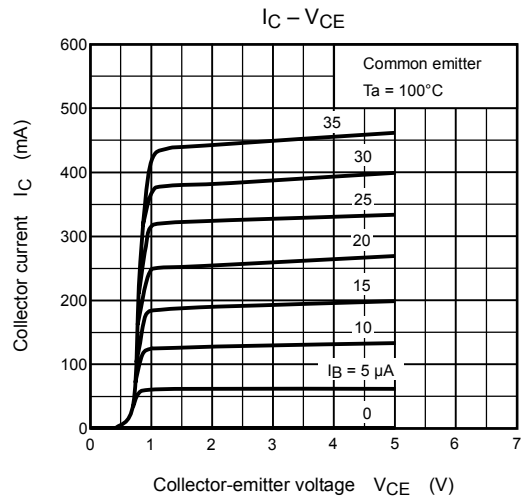
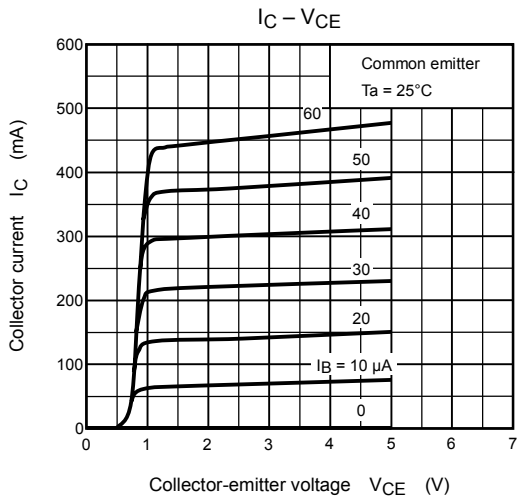
Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		$I_{CBO}$	$V_{CB} = 30\text{ V}, I_E = 0$	—	—	10	$\mu\text{A}$
Emitter cut-off current		$I_{EBO}$	$V_{EB} = 10\text{ V}, I_C = 0$	—	—	10	$\mu\text{A}$
Collector-emitter breakdown voltage		$V_{(BR)CEO}$	$I_C = 10\text{ mA}, I_B = 0$	30	—	—	V
DC current gain		$h_{FE}$	$V_{CE} = 2\text{ V}, I_C = 150\text{ mA}$	4000	—	—	
Collector-emitter saturation voltage		$V_{CE(sat)}$	$I_C = 1\text{ A}, I_B = 1\text{ mA}$	—	—	1.5	V
Base-emitter saturation voltage		$V_{BE(sat)}$	$I_C = 1\text{ A}, I_B = 1\text{ mA}$	—	—	2.2	V
Switching time	Turn-on time	$t_{on}$		—	0.20	—	$\mu\text{s}$
	Storage time	$t_{stg}$		—	0.6	—	
	Fall time	$t_f$		$I_{B1} = -I_{B2} = 1\text{ mA}$ $I_C = 1\text{ A}, \text{duty cycle} \leq 1\%$	—	0.3	

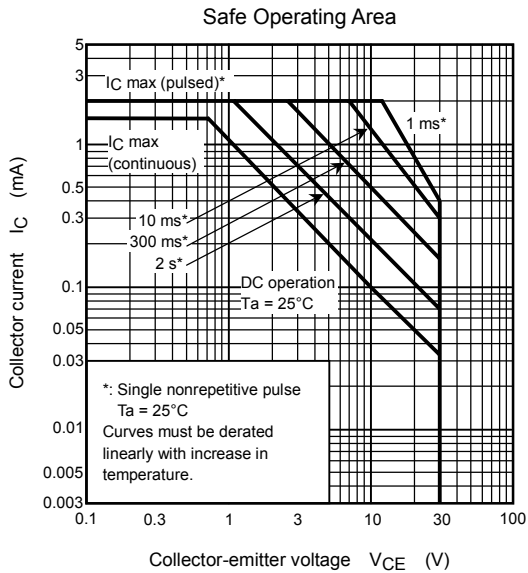
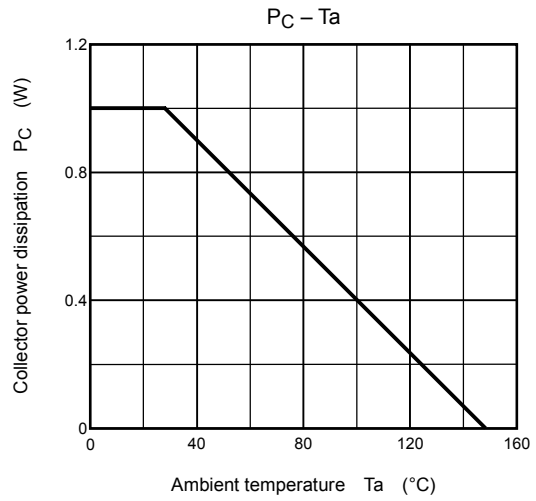
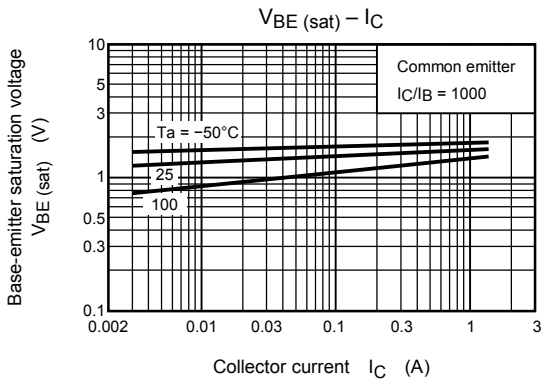
## Marking



## Explanation of Lot No.







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